# DATA SHEET



# ESD NOISE CLIPPING DIODE

## LOW CAPACITANCE TYPE ELECTROSTATIC DISCHARGE NOISE CLIPPING DIODE (QUARTO TYPE: COMMON ANODE) 5-PIN SUPER SMALL MINI MOLD

## DESCRIPTION

The NNCD6.8PH is a diode developed for ESD (Electrostatic Discharge) absorption. Based on the IEC-61000-4-2 test on electromagnetic interference (EMI), the diode assures an endurance of no less than 30 kV, thus making itself most suitable for external interface circuit protection.

With four elements mounted in the 5-PIN super mini mold package, the product can cope with more high density assembling.

## FEATURES

- Base on the electrostatic discharge immunity test (IEC 61000-4-2), the product assures the minimum endurance of 30 kV.
- With four elements in the MINI MOLD package, the products can achieve high density and automatic packaging.

## **APPLICATIONS**

- External interface circuit ESD absorption
- · Circuits for waveform clipper, surge absorber

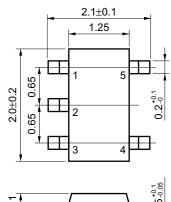
## MAXIMUM RATINGS ( $T_A = 25^{\circ}C$ )

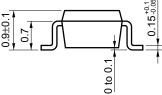
#### ITEM SYMBOL RATING REMARK UNIT Power Dissipation Ρ 200 mW Total Surge Reverse Power PRSM 85 (t = 10 µs 1 pulse) W °C **Junction Temperature** Tj 150 °C Storage Temperature Tstg -55 to +150

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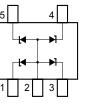
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## PACKAGE DIMENSION (Unit: mm)





## **ELECTRODE CONNECTION**



1. K1: Cathode 1

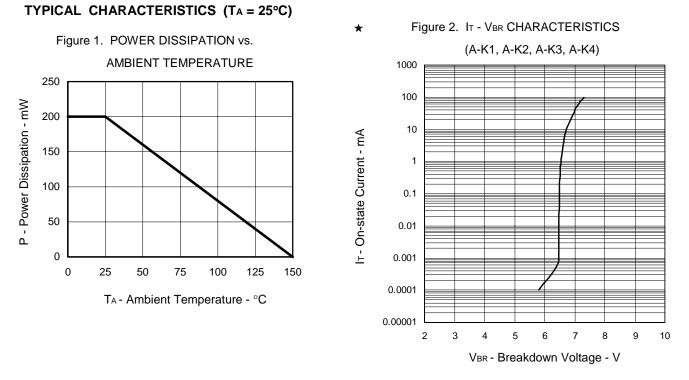
- 2. A : Anode (common)
- 3. K2: Cathode 2 4. K3: Cathode 3
- 5. K4: Cathode 4

TYPE No.	BREAKDOWN VOLTAGE <sup>Note1</sup>			CAPACITANCE		REVERSE		DYNAMIC IMPEDANCE <sup>Note2</sup>		ESD VOLTAGE Note3	
	VBR (V)			Ct (pF)		IR (μA)		Zz (Ω)		(kV)	
	MIN.	MAX.	l⊤(mA)	TYP.	Condition	MAX.	Vr (V)	MAX.	l⊤(mA)	MIN.	Condition
NNCD6.8PH	6.2	7.1	5	90	V <sub>R</sub> = 0 V f = 1 MHz	2	3.5	40	5	30	C = 150 pF R = 330 $\Omega$ Contact discharge

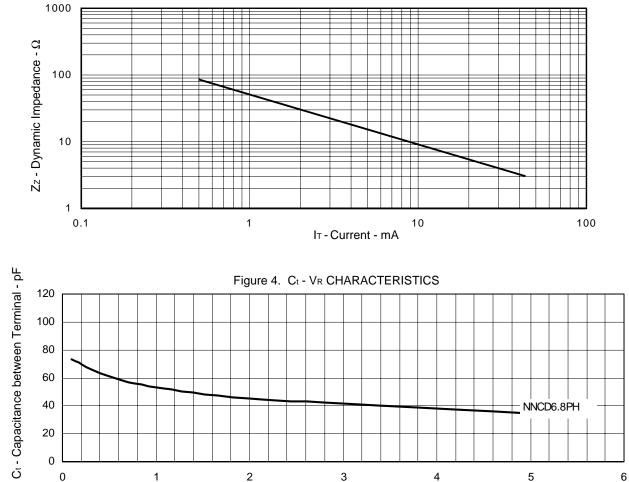
## ELECTRICAL CHARACTERISTICS (TA = 25°C) (A to K1, A to K2, A to K3, A to K4)

Notes 1. Tested with pulse (40 ms)

- **2**.  $Z_z$  is measured at  $I_T$  given a small A.C. signal.
- 3. Based upon with IEC 61000-4-2



## Figure 3. Zz - IT



VR - Reverse Voltage - V

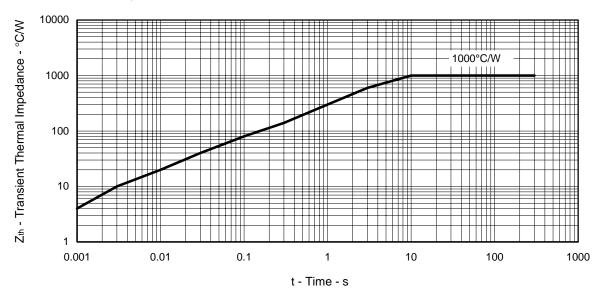
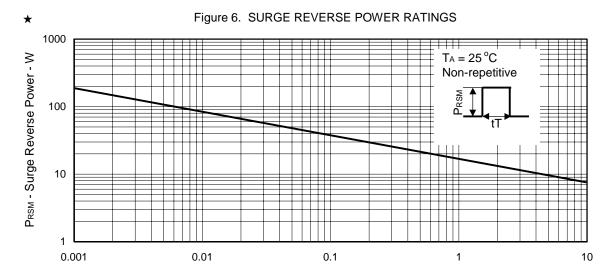


Figure 5. TRANSIENT THERMAL IMPEDANCE CHARACTERISTICS



tT - Pulse Width - ms

[MEMO]

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